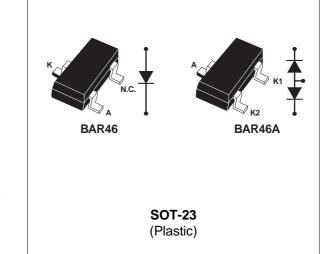


BAR46 BAR46AFILM

SMALL SIGNAL SCHOTTKY DIODES

FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- SURFACE MOUNT DEVICE



DESCRIPTION

High voltage Schottky rectifier suited for SLIC protection during the card insertion operation.

ABSOLUTE RATINGS(limiting values)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	100	V
lF	Continuous forward current	150	mA
P _{tot}	Power dissipation (note 1)	230	mW
T _{stg}	Maximum storage temperature range	- 65 to +150	°C
Tj	Maximum operating junction temperature *	150	°C
TL	Maximum temperature for soldering during	260	°C

Note 1: for double diodes, Ptot is the total dissipation of both diodes.

* :
$$\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$$
 thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction-ambient *	500	°C/W

^{*} Mounted on epoxy board, with recommended pad layout.

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Te	Min.	Тур.	Max.	Unit	
V_{BR}	Tj = 25 °C	$I_R = 100 \mu A$	100			V
V _F *	Tj = 25 °C	$I_F = 0.1 \text{ mA}$			0.25	V
	Tj = 25 °C	$I_F = 10 \text{ mA}$			0.45	
	Tj = 25 °C	$I_F = 250 \text{ mA}$			1	
I _R **	Tj = 25 °C	V _R = 1.5 V			0.5	μΑ
	Tj = 60 °C				5	
	Tj = 25 °C	V _R = 10 V			0.8	
	Tj = 60 °C				7.5	
	Tj = 25 °C	V _R = 50 V			2	
	Tj = 60 °C				15	
	Tj = 25 °C	V _R = 75 V			5	
	Tj = 60 °C				20	

Pulse test : * tp = 380 μ s δ < 2% ** tp = 5 ms, δ < 2%

DYNAMIC CHARACTERISTICS

Symbol	Test conditions			Min.	Тур.	Max.	Unit
С	Tj = 25 ℃	$V_R = 0 V$	F = 1MHz		10		pF
	Tj = 25 °C	V _R = 1 V			6		

Fig. 1: Forward current versus forward voltage at different temperatures (typical values).

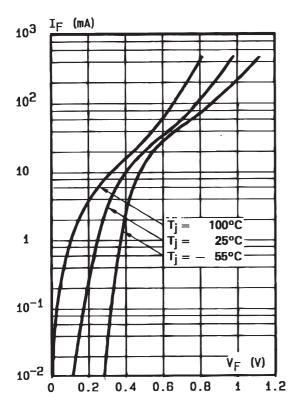


Fig. 3: Reverse current versus junction temperature (typical values).

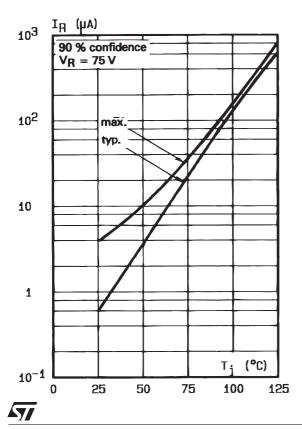


Fig. 2: Forward current versus forward voltage (typical values).

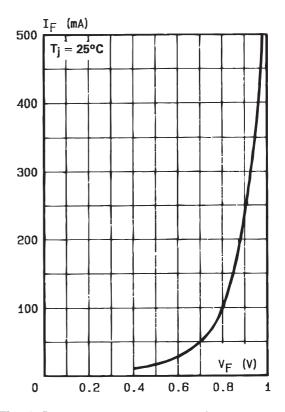
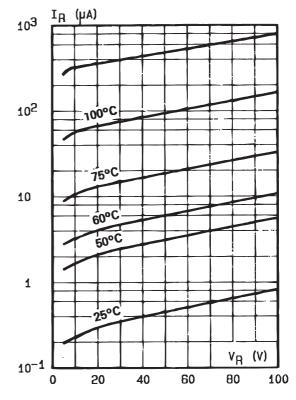
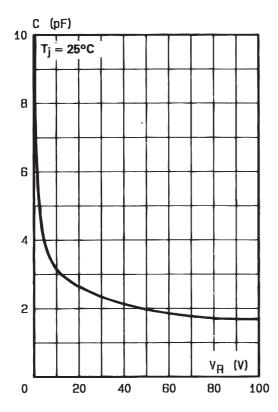


Fig. 4: Reverse current versus continuous reverse voltage (typical values).



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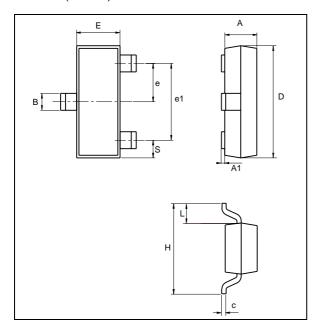
Fig. 5: Capacitance C versus reverse applied voltage V_R (typical values).



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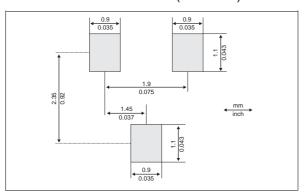
PACKAGE MECHANICAL DATA

SOT-23 (Plastic)



	DIMENSIONS					
REF.	Millin	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	0.89	1.4	0.035	0.055		
A1	0	0.1	0	0.004		
В	0.3	0.51	0.012	0.02		
С	0.085	0.18	0.003	0.007		
D	2.75	3.04	0.108	0.12		
е	0.85	1.05	0.033	0.041		
e1	1.7	2.1	0.067	0.083		
Е	1.2	1.6	0.047	0.063		
Н	2.1	2.75	0.083	0.108		
L	0.6 typ.		0.024 typ.			
S	0.35	0.65	0.014	0.026		

FOOT PRINT DIMENSIONS (Millimeter)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR46	S46	SOT-23	0.01g	3000	Tape & reel
BAR46AFILM	A46	SOT-23	0.01g	3000	Tape & reel

■ Epoxy meets UL94,V0

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